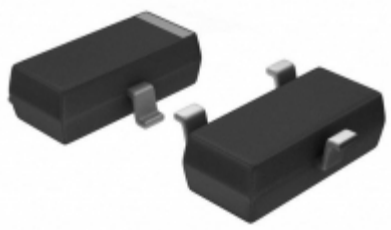

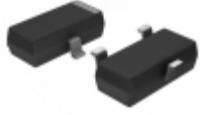


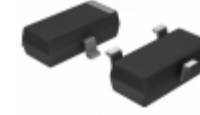




	FJV3108RMTF	
	Hersteller-Teilenummer:	FJV3108RMTF
	Hersteller / Marke:	Fairchild/ON Semiconductor
	Teil der Beschreibung:	TRANS PREBIAS NPN 200MW SOT23-3
	Datenblätter:	1.FJV3108RMTF.pdf 2.FJV3108RMTF.pdf
	RoHs Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, 76250 pcs Stock Available.	
Lieferrn von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FJV3108RMTF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	76250 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	56 @ 5mA, 5V
Frequenz - Übergang	250MHz
Widerstand - Base (R1) (Ohm)	47k
Widerstand - Emitter-Basis (R2) (Ohm)	22k
Verpackung	Tape & Reel (TR)

FJV3108RMTF ist neu im Original, Suche FJV3108RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3108RMTF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3108RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV3108RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3106RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3109RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3107RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>
 <p>FJV3107RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3105RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3109RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3109R FAIRCHI FJV3109R FAIRCHI</p>

heiße Teile

Mehr

⚙ FJV1845EMTF	➔ FJV1845EMTF	➔ FJV1845FMTF	D FJV1845FMTF	➔ FJV1845PMTF
⊣ FJV1845PMTF	⚙ FJV1845UMTF	D FJV1845UMTF	➔ FJV3101RLIMTF	➔ FJV3101RMTF
⚙ FJV3101RMTF	⊣ FJV3102RMTF	⚙ FJV3102RMTF	➔ FJV3103RMTF	➔ FJV3103RMTF
D FJV3104RMTF	⚙ FJV3104RMTF	⊣ FJV3105RMTF	⚙ FJV3105RMTF	➔ FJV3106RMTF
➔ FJV3106RMTF	➔ FJV3107RMTF	⚙ FJV3107RMTF	⊣ FJV3108RMTF	➔ FJV3109R
➔ FJV3109RMTF	➔ FJV3109RMTF	D FJV3110RMTF	⚙ FJV3110RMTF	⊣ FJV3111RMTF
⚙ FJV3111RMTF	D FJV3112RMTF	➔ FJV3112RMTF	➔ FJV3113RMTF	➔ FJV3113RMTF
⊣ FJV3114RMTF	⚙ FJV3114RMTF	➔ FJV3115RMTF	➔ FJV3115RMTF	➔ FJV4101RMTF
⚙ FJV4101RMTF	⊣ FJV4102RLIMTF	⚙ FJV4102RMTF	D FJV4102RMTF	➔ FJV4103RMTF
➔ FJV4103RMTF	⚙ FJV4104RMTF	⊣ FJV4104RMTF	⚙ FJV4105RMTF	➔ FJV4105RMTF

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited